



SPECIFICATION FOR RoHS 6 COMPLIANT SMT VCTCXO MtronPTI P/N M6161S022

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Frequency of Operation	Fo		10.0000000		MHz	
Initial Accuracy	Fi	-1.0		+1.0	ppm	@ 25°C
Frequency Stability	$\Delta F/F$	-2.5		+2.5	ppm	Over operating temperature $(F_{Max} - F_{Min})/2$
Frequency Vs. Reflow		-1.0		+1.0	ppm	
Frequency Vs. Supply			± 0.02	± 0.1	ppm	For 5% supply change
Frequency Vs. Load			± 0.02	± 0.1	ppm	For 5% load change
Operating Temperature	TA	-40		+85	°C	
Operating Voltage	V _{DD}	3.135	3.3	3.465	V	
Operating Current	I _{DD}			3.0	mA	
Output Type		HC	MOS Compatib	е		
Output Load				15	pF	
Symmetry (duty cycle)	T _{DC}	45	50	55	%	@ 50% of V _{DD}
Logic "1" Level	Vон	80% V _{DD}			V	HCMOS load
Logic "0" Level	Vol			20% V _{DD}	V	HCMOS load
Rise/Fall Time	T_R/T_F			7	nS	From 10% to 90% V _{DD}
Frequency Adjust		± 9.2				Over Control Voltage
Range		± 9.2			ppm	Range. Pad 10.
Control Voltage Range		0.3	1.65	3.0	V	Pad 10
Linearity				5	%	Positive slope. Pad 10
Input Leakage Current		-50		+50	μA	Pad 10
Input Resistance		100			kΩ	Pad 10
Modulation Bandwidth		2			kHz	Pad 10
Tri-state Enable Logic		70% V _{DD}			V	Pad 8
Tri-state Disable Logic				30% V _{DD}	V	Pad 8. Output to high-Z
Phase Noise			-102		dBc/Hz	@ 10 Hz
			-132		dBc/Hz	@ 100 Hz
			-150		dBc/Hz	@ 1 kHz
			-155		dBc/Hz	@ 10 kHz
			-156		dBc/Hz	@ 100 kHz

Environmental Conditions:

Shock	Per MIL-STD-202, Method 213, Condition C (100 g's, 6 ms duration, ½ sinewave)
Vibration	Per MIL-STD-202, Method 201 & 204 (10 g's from 10-2000 Hz)
Hermeticity	Per MIL-STD-202, Method 112 (1 x 10 ⁻⁸ atm cc/s of Helium) (Crystal Only)
Storage Temperature	-55°C to +125°C
Solderability	Per EIAJ-STD-002
Max. Soldering Conditions	See solder profile, Figure 1
Package Type	5.0 x 7.0 x 2.0 mm, 10-pad Ceramic Leadless Chip Carrier





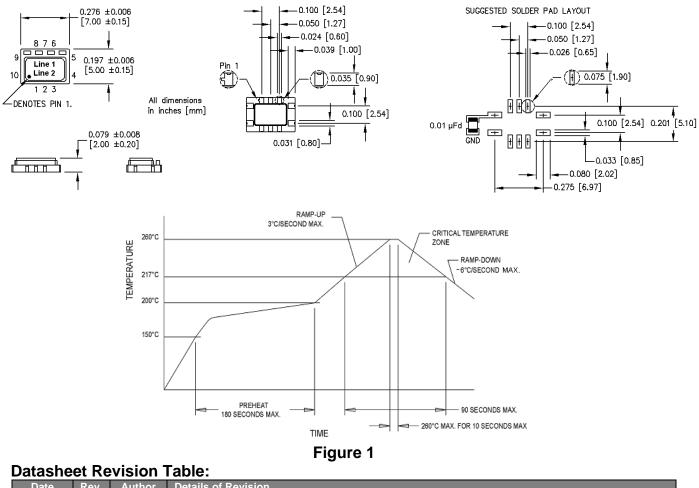
SPECIFICATION FOR RoHS 6 COMPLIANT SMT VCTCXO MtronPTI P/N M6161S022

Mechanical, Marking and Layout Information:

Pad	Function
1	N/C or Ground (suggested)
2	N/C
3	N/C
4	Ground/Case
5	Output
6	N/C
7	N/C
8	Tri-state
9	+V _{DD}
10	Control Voltage
	· · · · · ·

Par	t Marking
Line 1	M61 ym
Line 2	10M000

Legend		
Y	Year	
m	Month	



Date	Rev.	Author	Details of Revision
4/5/13	0	MM	Original release.